

SiC Schottky Barrier Rectifier

Reverse Voltage - 650V

Forward Current - 10A

Features

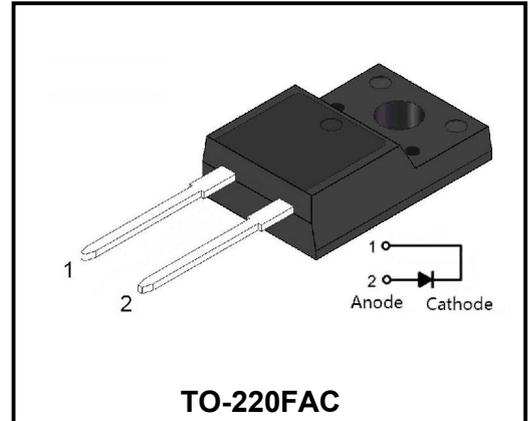
- ◆ Reverse withstand voltage 650V
- ◆ Zero reverse recovery current
- ◆ High working frequency
- ◆ Switch characteristics are not affected by temperature
- ◆ Fast switching speed
- ◆ Positive temperature coefficient of positive pressure drop

Advantages

- ◆ Very low switching loss
- ◆ Higher efficiency
- ◆ Low dependence of the system on the heat sink
- ◆ No thermal collapse in parallel devices

Application

- ◆ Switching mode power supply, AC/DC converter
- ◆ Power factor correction
- ◆ Motor drive
- ◆ PV inverter and wind turbine



TO-220FAC

Absolute Maximum Rating (Ta=25°C)

Parameter	Symbol	Test conditions	Value	Unit
Peak repetitive reverse voltage	V_{RRM}		650	V
Working Peak Reverse voltage	V_{RWM}		650	V
DC Blocking Voltage	V_{DC}		650	V
Average rectified output current	$I_{F(AV)}$	Ta=25°C Ta=125°C Ta=150°C	22 17.5 10	A
Forward repetitive peak current	I_{FRM}	T _C =25°C, tp=10ms, Half Sine Wave T _C =110°C, tp=10ms, Half Sine Wave	51 46	A
Forward surge current	I_{FSM}	T _C =25°C, tp=10ms, Half Sine Wave T _C =110°C, tp=10ms, Half Sine Wave	67 61	A
Power dissipation	P_{tot}	Ta=25°C Ta=110°C	60 26	W
Junction temperature	T _j		-55 ~ +175	°C
Storage temperature	T _{stg}		-55 ~ +175	°C

Thermal characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal Resistance - Junction to Case	$R_{\theta JC}$		2.5		$^{\circ}C/W$

Electrical Characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Forward voltage	V_F	$I_F = 10 A, T_j = 25^{\circ}C$ $I_F = 10 A, T_j = 175^{\circ}C$		1.4 1.66	1.6 2.0	V
Reverse current	I_R	$V_R = 650V, T_j = 25^{\circ}C$ $V_R = 650V, T_j = 175^{\circ}C$		2 10	50 200	μA
Total capacitive charge	Q_C	$V_R = 400V, I_F = 10A$ $di/dt = 500A/\mu s, T_j = 25^{\circ}C$		38		nC
Total capacitance	C	$V_R = 0V, T_j = 25^{\circ}C, f = 1MHz$ $V_R = 200V, T_j = 25^{\circ}C, f = 1MHz$ $V_R = 400V, T_j = 25^{\circ}C, f = 1MHz$		683 88 82		pF

Typical Characteristics

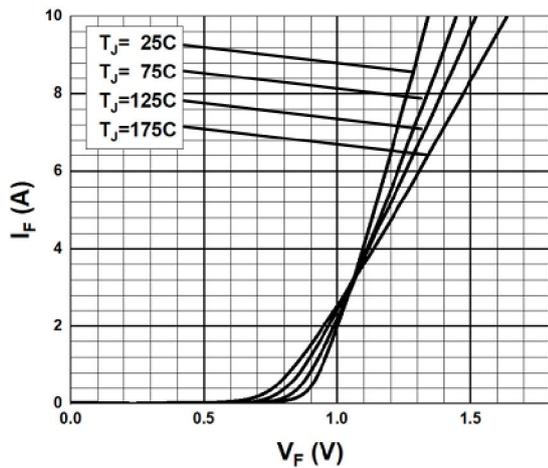


Figure 1. Forward Characteristics

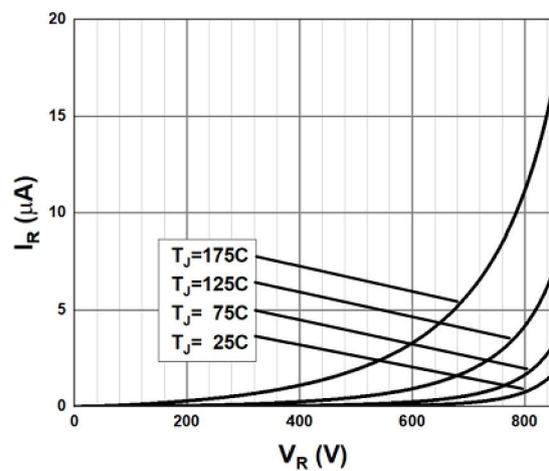


Figure 2. Reverse Characteristics

Typical Characteristics

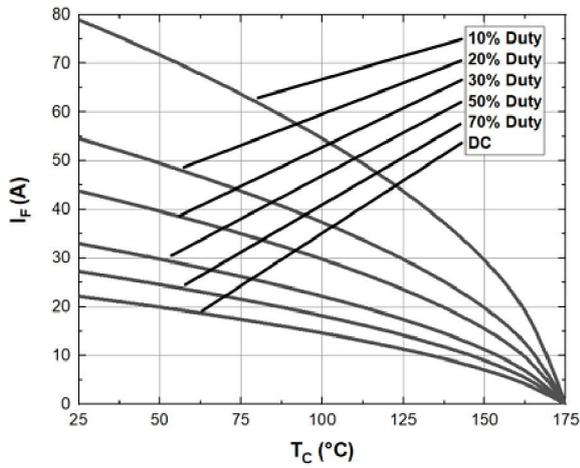


Figure 3. Current Derating

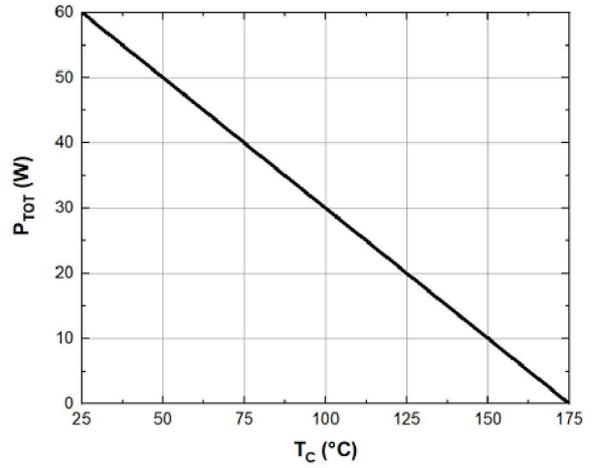


Figure 4. Power Derating

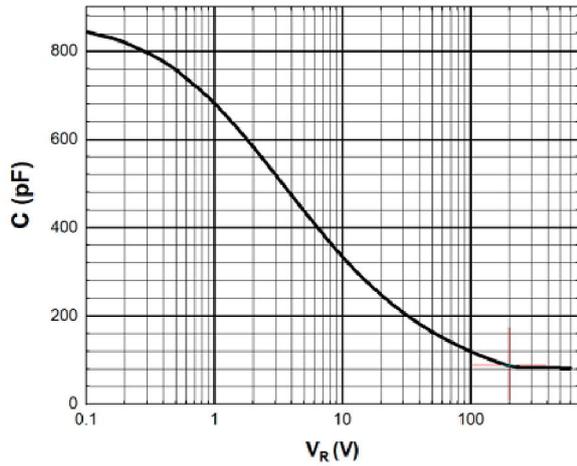


Figure 5. Capacitance vs reverse voltage

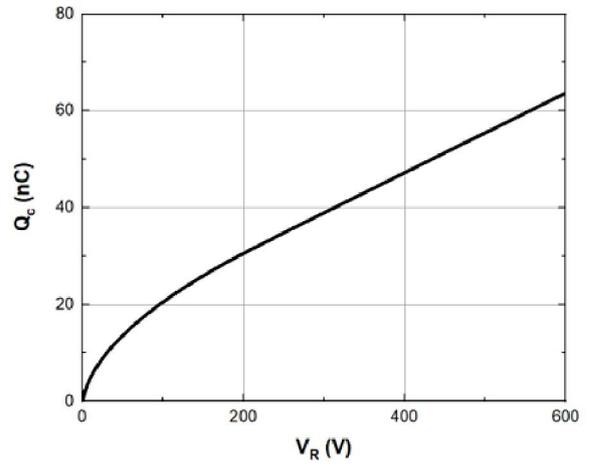


Figure 6. Recovery Charge vs Reverse Voltage

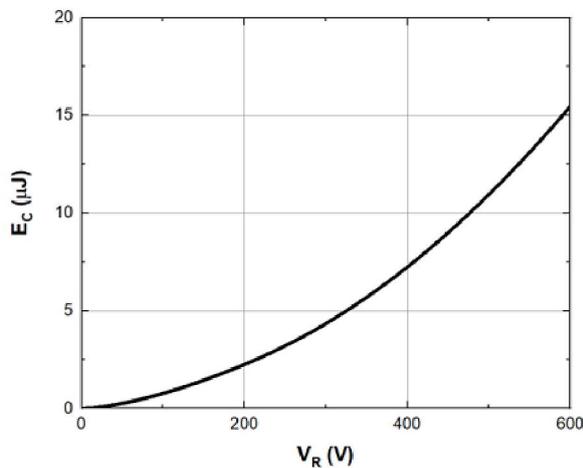


Figure 7. Capacitance stored Energy

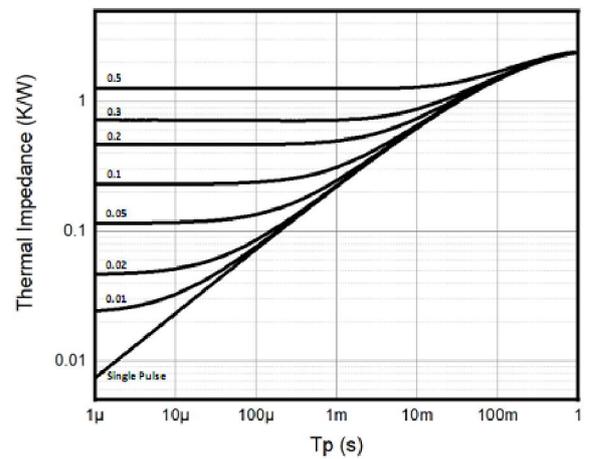


Figure 8. Thermal Impedance

Package Dimensions

TO-220FAC

